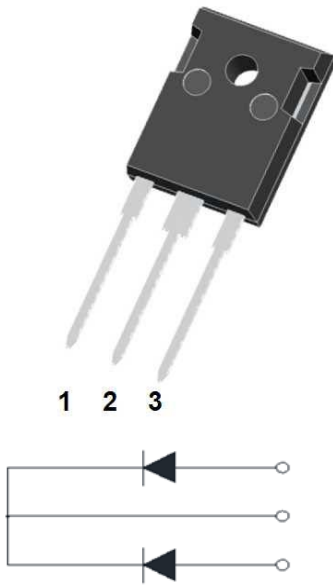


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-247AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■Maximum Ratings (T_a=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBR30200PT
Device marking code			MBR30200PT
Repetitive Peak Reverse Voltage	V _{RRM}	V	200
Average Rectified Output Current @60Hz sine wave, R-load, T _c =148°C	I _o	A	30
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C	I _{FSM}	A	250
Current Squared Time @1ms≤t≤8.3ms T _j =25°C	I ² t	A ² s	260
Storage Temperature	T _{stg}	°C	-55 ~ +175
Junction Temperature	T _j	°C	-55 ~ +175

■Electrical Characteristics

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	Min	Typ	Max
Peak Forward Voltage	V _{FM}	V	I _{FM} =15.0A T _j =25°C	0.5	0.83	0.9
			I _{FM} =15.0A T _j =125°C	-	0.745	0.82
DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _{RRM} T _j =25°C	-	-	0.1
	I _{RRM2}		V _{RM} =V _{RRM} T _j =125°C	-	-	20
Junction capacitance	C _j	pF	1MHz Applied Voltage and Reverse of 4.0 V.D.C	150	240	500

Note1:Pulse test:300uS pulse width,1% duty cycle

Note2:Pulse test:pulse width 40mS



MBR30200PT

■ Thermal Characteristics (T_a=25°C Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBR30200PT
Thermal Resistance	Between junction and ambient	R _{θJ-A}	°C/W	50.0
	Between junction and case	R _{θJ-C}	°C/W	1.0

■ Characteristics (Typical)

FIG1: I_o -T_c Curve

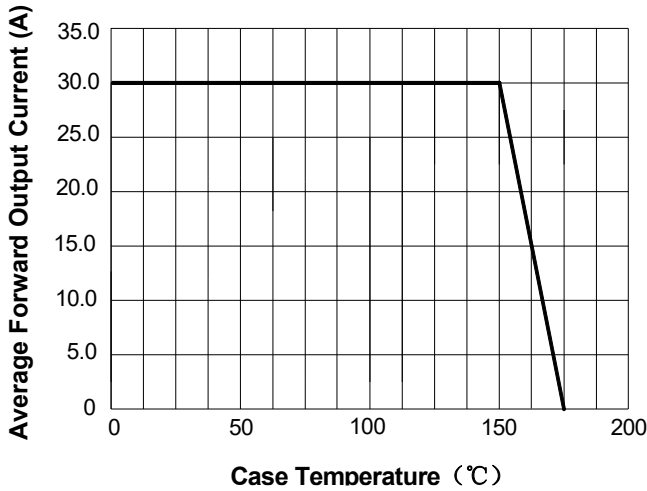


FIG2: Surge Forward Current Capability

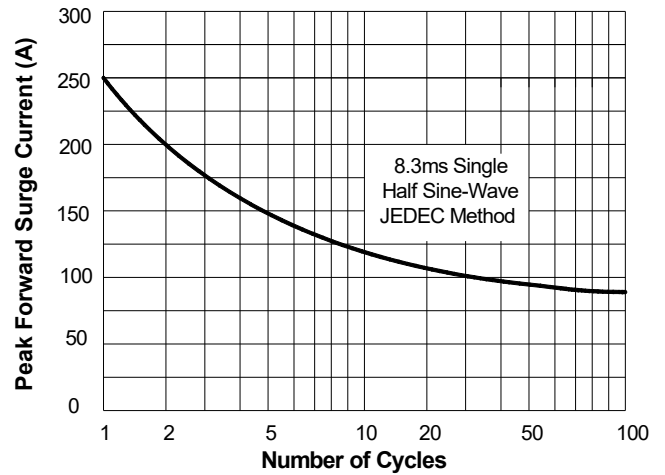


FIG3: Forward Voltage

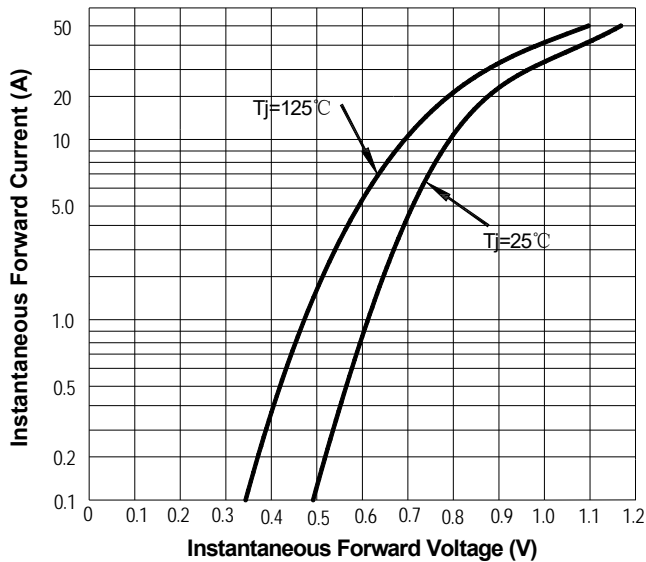
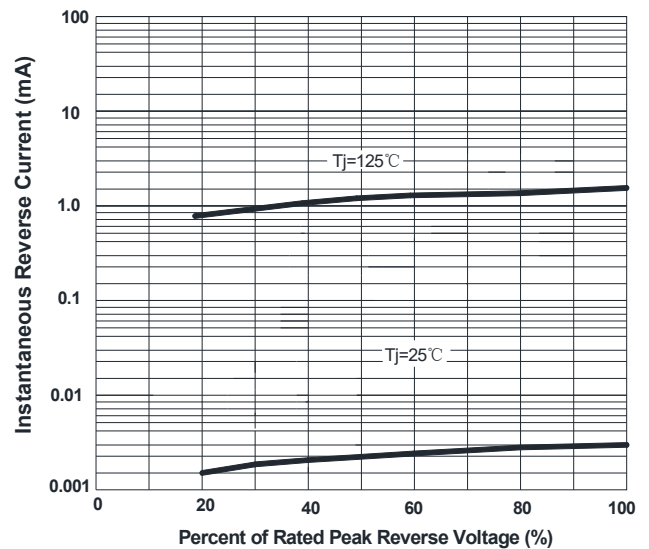


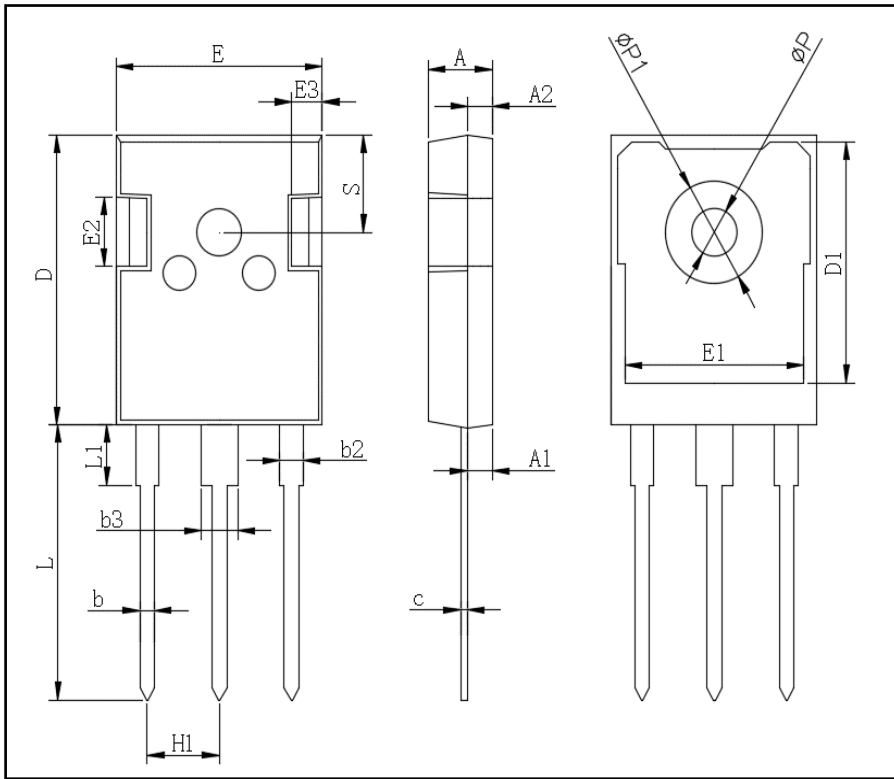
FIG4: Instantaneous Reverse Characteristics





MBR30200PT

■Outline Dimensions



TO-247AB		
Dim	Min	Max
A	4.80	5.20
A1	2.21	2.61
A2	1.85	2.15
b	1.0	1.4
b2	1.91	2.21
C	0.5	0.7
D	20.70	21.30
D1	16.25	16.85
E	15.50	16.10
E1	13.0	13.6
E2	4.80	5.20
E3	2.30	2.70
L	19.62	20.22
L1	-	4.30
φP	3.40	3.80
φP1	-	7.30
S	6.15TYP	
H1	5.44TYP	
b3	2.80	3.20



MBR30200PT

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